

CDBW0520L-G - CDBW0540-G

Voltage: 20-40 Volts

Current: 0.5 Amp

RoHS Device



Feature

Low turn-on voltage

Fast switching

PN junction guard ring for transient and ESD protection

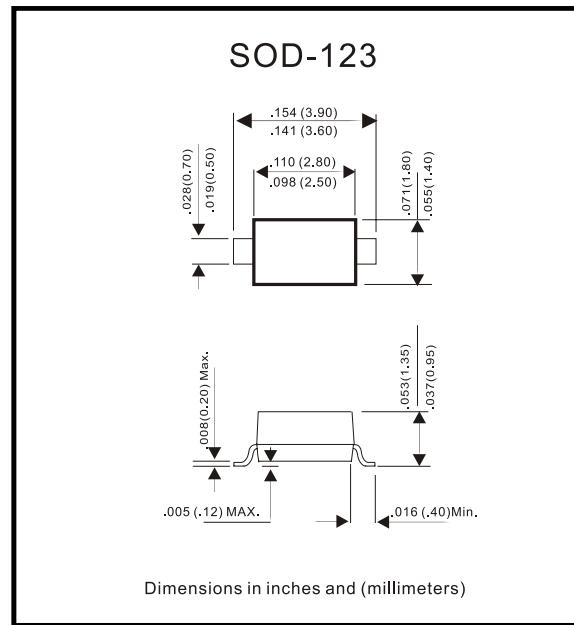
Mechanical data

Case: SOD-123, molded plastic

Terminals: solderable per MIL-STD-750, method 2026

Polarity: Indicated by cathode band

Approx. Weight: 0.008 grams



Maximum Ratings and Electrical Characteristics

Parameter	Symbol	CDBW0520L-G	CDBW0530-G	CDBW0540-G	Unit
Max. Repetitive Peak Reverse Voltage	V _{RRM}	20	30	40	V
DC Blocking Voltage	V _{DC}	20	30	40	V
Max. RMS Voltage	V _{RMS}	14	21	28	V
Peak Surge Forward Current 8.3ms single half sine-wave Sine-wave superimposed on Rate load (JEDEC)	I _{FSM}		5.5		A
Max. AverageForward Current	I _o		0.5		A
Max. Forward Voltage	V _F	0.3@ I _F =0.1A 0.385@ I _F =0.5A	0.375@ I _F =0.1A 0.430@ I _F =0.5A	0.51@ I _F =0.5A 0.62@ I _F =1.0A	V
Max. Reverse Current	I _R	0.075 @ V _R =10V 0.25 @ V _R =20V	0.02 @ V _R =15V 0.13 @ V _R =30V	0.01 @ V _R =20V 0.02 @ V _R =40V	mA
Max. Thermal Resistance	R _{θ JA} R _{θ JL}		206 150		°C/W
Max. Operating junction temperature	T _j		125		°C
Storage temperature	T _{STG}		-55 to +125		°C

Note 1: Thermal resistance from junction to ambient and junction to lead Mounted on PCB with 0.2 x 0.2inch² copper pad areas

REV.:A

RATING AND CHARACTERISTIC CURVES (CDBW0520L-G-0540-G)

Fig. 1 - Forward Characteristics

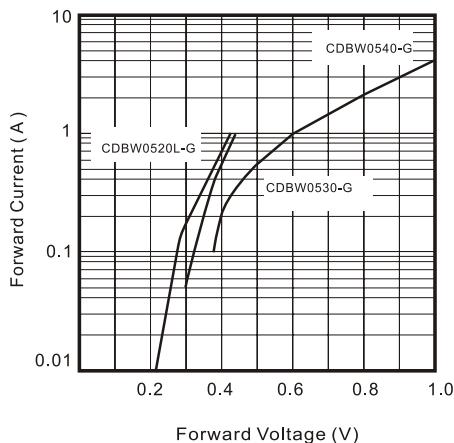


Fig. 2 - Current Derating Curve

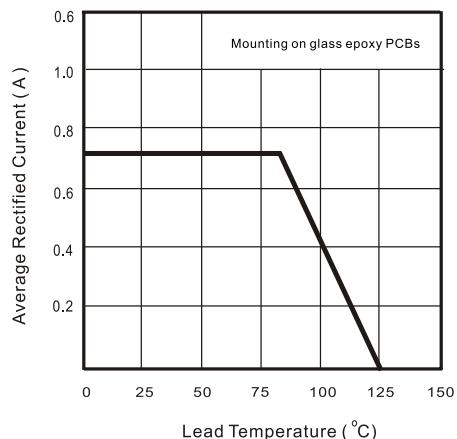


Fig. 3 - Total Capacitance vs Reverse Voltage

